

# Growth of Al<sub>2</sub>O<sub>3</sub> whiskers by vapour-phase reactions

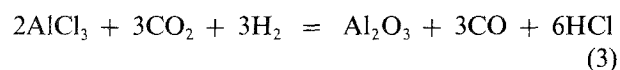
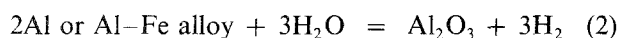
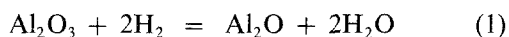
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Needle-like or wool-like Al<sub>2</sub>O<sub>3</sub> whiskers can be grown on a substrate by the hydrolysis of aluminium fluoride vapour. Effects of the growth conditions on the morphology of the crystals and growth processes of the whisker were investigated, and the optimum growth condition of whiskers was examined. Adequate vapour pressure conditions of the reactant gases for the growth of the wool-like whisker were found to be  $P_{\text{AlF}_3} \times P_{\text{H}_2\text{O}}^{3/2} < 3.0 \times 10^{-3}$  (torr<sup>2</sup>). Aluminium oxyfluoride was assumed to be the most probable intermediate species for the growth of Al<sub>2</sub>O<sub>3</sub> whiskers. A variety of crystal morphologies are also shown and described with respect to the experimental conditions.

## 1. Introduction

The preparation of oxide whiskers has been extensively investigated over the last several decades using vapour-phase reactions. Among these, the growth of Al<sub>2</sub>O<sub>3</sub> whiskers by vapour phase reaction has been reported by several investigators [1-4], using the following chemical reactions:



Webb and Forgang [2] obtained Al<sub>2</sub>O<sub>3</sub> whiskers of 1 to 3 mm long and 3 to 50 μm diameter using Reaction 2. Wiedemann and Sturzenegger [3] synthesized Al<sub>2</sub>O<sub>3</sub> whiskers, using aluminium-containing alloys in wet hydrogen to lower the partial pressure of aluminium. Campbell [4] has developed a continuous formation process for Al<sub>2</sub>O<sub>3</sub> whiskers, using Reaction 3.

In the reactions described above, aluminium suboxides, especially Al<sub>2</sub>O, have been considered to be the most probable intermediate species for the vapour-phase mass transport. Many experiments on the growth mechanism of alumina whiskers have been carried out [5-9], but the mechanism still remains to be solved. Alumina crystals have been designated as A<sub>1</sub>, A<sub>2</sub>, A/C and C whisker, because of their relationship to the crystal axes in the hexagonal system.

In a preceding paper [10], it was found that alumina crystals, which had various morphologies, i.e. wool-like whiskers, needle-like whiskers, jointed needle-like crystals, coagulated powder and thin films, could be prepared from the AlF<sub>3</sub>-H<sub>2</sub>O system, depending on

growth conditions. In that paper, the fibrous crystals with diameters greater than about 5 μm were called needle-like whiskers, and those below 5 μm were called wool-like whiskers, even if both morphologies were similar. In the present work, the growth conditions and thermodynamics for growing whiskers were studied in detail by changing the vapour pressures of AlF<sub>3</sub> and H<sub>2</sub>O. A variety of crystal morphologies was also examined with respect to the experimental conditions.

## 2. Experimental details

The apparatus has been previously described in detail [10]. The graphite tube, which was used as a reactor, consisted of a region for vaporization of AlF<sub>3</sub> and a region for growth of Al<sub>2</sub>O<sub>3</sub>. AlF<sub>3</sub>, which was evaporated in a furnace at a given temperature ranging from 710 to 820°C, was introduced into the reactor with argon gas and reacted with water vapour, introduced through another inlet with argon gas, on a polycrystalline alumina substrate. The desired vapour pressure of H<sub>2</sub>O was prepared by bubbling argon gas through water at 0°C and diluting the moist gas by appropriate mixing with dry argon gas. All experiments were carried out at atmospheric pressure. The experimental conditions were as follows: growth temperature 1400°C, growth time 3 h, AlF<sub>3</sub> vapour pressure  $1.0 \times 10^{-4}$  to  $1.0 \times 10^{-2}$  torr, H<sub>2</sub>O vapour pressure  $8 \times 10^{-3}$  to  $5 \times 10^{-1}$  torr, argon gas flow rate 150 to 400 ml min<sup>-1</sup>. The morphology of the crystals was examined by optical microscopy and scanning electron microscopy. The products were identified by X-ray and electron diffraction patterns. The impurities in the whiskers were detected with an X-ray microanalyser.

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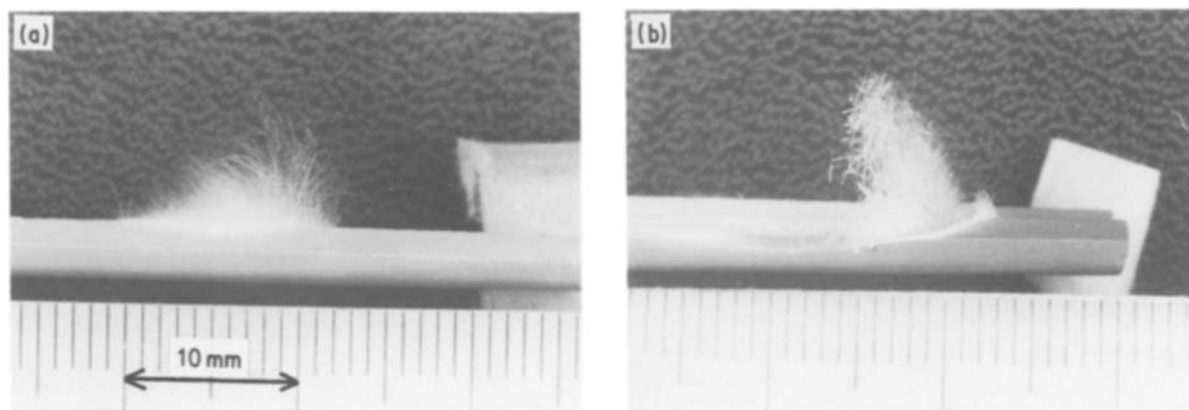


Figure 1 (a) Wool-like whiskers and (b) needle-like whiskers formed on the alumina substrate.

### 3. Results and discussion

#### 3.1. Influence of growth conditions on crystal morphology

It was found that the pressure level needed to be below a critical value in order to obtain only whiskers and to eliminate the formation of platelets and dendrites. Many whiskers grew straight from suitable sites on the surface of the substrate, as shown in Fig. 1. Wool-like whiskers were usually 1 to 4  $\mu\text{m}$  diameter and several millimetres long, whereas needle-like whiskers were 10 to 30  $\mu\text{m}$  diameter and 5 to 12 mm long. This length is approximately equal to the diameter of the reactor. The morphology of the grown crystals depended strongly on the growth conditions. At first, the influences of vapour pressure of  $\text{H}_2\text{O}$  (expressed as  $P_{\text{H}_2\text{O}}$ ) and the flow rate of argon gas containing  $\text{AlF}_3$  (expressed as  $\text{Ar}(\text{AlF}_3)$ ) on the morphology were investigated. The flow rate of the moist argon gas ( $\text{Ar}(\text{H}_2\text{O})$ ) and  $P_{\text{AlF}_3}$  were kept constant at  $150 \text{ ml min}^{-1}$  and  $7.6 \times 10^{-2}$  torr, respectively. It was found that  $P_{\text{H}_2\text{O}}$  for the growth of wool-like whiskers needed to be below about  $5 \times 10^{-2}$  torr. At vapour pressures above this value, the number of wool-like whiskers tended to decrease with increase in  $P_{\text{H}_2\text{O}}$ , in comparison to the number of needle-like whiskers which

tended to increase remarkably. Fig. 2 shows the relation between  $P_{\text{AlF}_3}$  and  $P_{\text{H}_2\text{O}}$  for whisker growth at constant  $\text{Ar}(\text{AlF}_3)$  and  $\text{Ar}(\text{H}_2\text{O})$  flow rates of 250 and  $150 \text{ ml min}^{-1}$ , respectively. The correlation between vapour pressures of  $\text{AlF}_3$  and  $\text{H}_2\text{O}$  was deduced, as mentioned below, from the experimental data. Suitable vapour pressures of  $\text{AlF}_3$  and  $\text{H}_2\text{O}$  for the growth of wool-like whiskers were below about  $8 \times 10^{-2}$  and about  $10^{-1}$  torr, respectively. At a constant  $P_{\text{AlF}_3}$ , the relative number of wool-like whiskers formed tended to decrease with increase in  $P_{\text{H}_2\text{O}}$ . It was found that a higher  $P_{\text{AlF}_3}$  required a lower  $P_{\text{H}_2\text{O}}$  to form mainly wool-like whiskers. Increasing both  $P_{\text{AlF}_3}$  and  $P_{\text{H}_2\text{O}}$  simultaneously caused morphological change of the grown crystals from wool-like to needle-like whiskers.

#### 3.2. Growth process

The formation of alumina by the reaction of  $\text{AlF}_3$  with  $\text{H}_2\text{O}$  may be represented by the following overall reaction:



Where  $\Delta G^\circ = -39.5 \text{ kcal mol}^{-1}$  at 1700 K. As previously discussed,  $\text{AlOF}$  was considered to be the most probable intermediate species in the reaction from

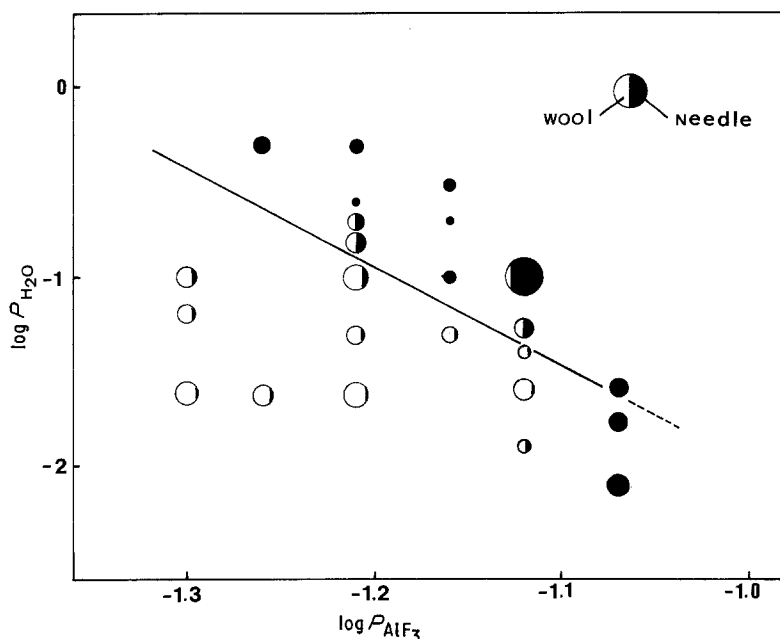


Figure 2 Relation between  $P_{\text{AlF}_3}$  and  $P_{\text{H}_2\text{O}}$  for whisker growth;  $\text{Ar}(\text{AlF}_3) = 250 \text{ ml min}^{-1}$ ,  $\text{Ar}(\text{H}_2\text{O}) = 150 \text{ ml min}^{-1}$ . The size of the circles represents the relative yield of whiskers obtained, and the black and white areas represent the relative ratios of needle-like whiskers and wool-like whiskers, respectively.

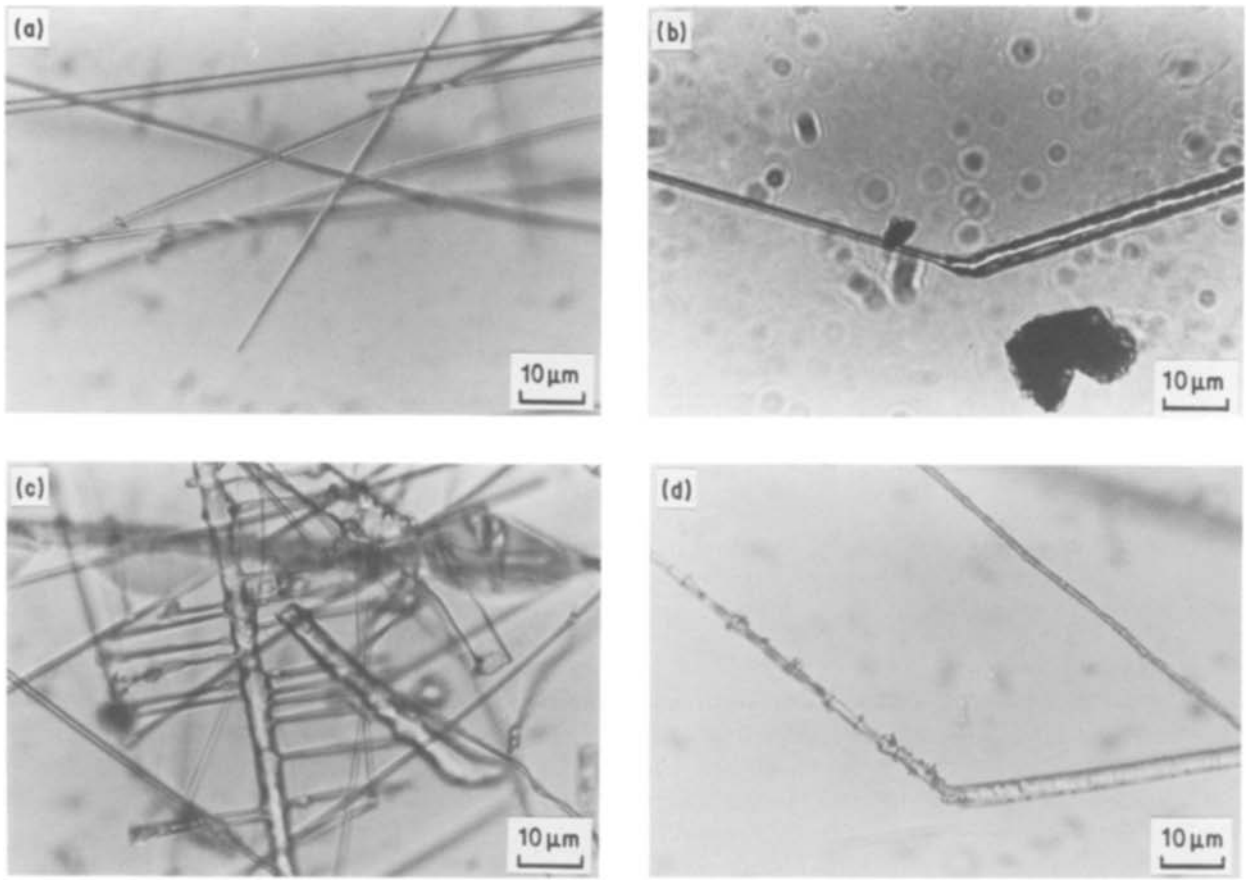
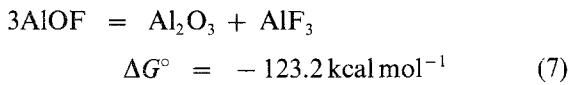
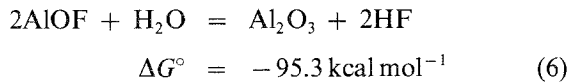


Figure 3 Optical micrographs of wool-like whiskers: (a) straight whiskers; (b, c) kinked whiskers; (d) branched whiskers.

thermodynamical calculations. The vapour pressure of  $\text{Al}_2\text{O}_3$ , which is usually considered to be the predominant intermediate species, is about one-twentieth that of  $\text{AlOF}$  in the conditions of this work. Hence, the following reactions have to be considered:



where  $\Delta G^\circ = 30.4 \text{ kcal mol}^{-1}$  at 1700 K. Since the free energy change in Reaction 5 is positive, the products will be unstable. If we considered the possible deposition reactions and their free energies, the following reactions may occur:



It was deduced that the disproportionation reaction of  $\text{AlOF}$ , such as Reaction 7, might occur preferentially under the conditions where the ratio of  $\text{AlF}_3$  to  $\text{H}_2\text{O}$  was larger than that of  $\text{Al}/\text{O}$  in  $\text{Al}_2\text{O}_3$ , i.e.  $2/3$ .

For whisker growth, the control of supersaturation is a prime consideration, because the degree of supersaturation,  $\Sigma_T$ , is expressed by the partial pressure,  $P_a$ , of the growth species ( $\text{AlOF}$ ) produced by the reaction, and the equilibrium partial pressure,  $P_e$ , of the growth species at a given temperature:

$$\Sigma_T = P_a/P_e \quad (8)$$

Here, the growth of alumina whiskers is implicitly assumed to proceed via Reactions 5 and 6. From

Reaction 5,

$$P_a(\text{AlOF}) = \frac{K_2 P_{\text{AlF}_3} P_{\text{H}_2\text{O}}}{P_{\text{HF}}^2} \quad (K_2 = \text{equilibrium const.}) \quad (9)$$

From Reaction 6,

$$P_e(\text{AlOF}) = \frac{P_{\text{HF}}}{K_3^{1/2} P_{\text{H}_2\text{O}}^{1/2}} \quad (K = \text{equilibrium const.}) \quad (10)$$

Hence,

$$\Sigma_T = \frac{K_2 P_{\text{AlF}_3} P_{\text{H}_2\text{O}}^{3/2} K_3^{1/2}}{P_{\text{HF}}^3} \quad (11)$$

Since  $K_1 = K^2 K_3$  ( $K_1$  is the equilibrium constant of Reaction 4), Reaction 11 can be expressed as

$$\Sigma_T = \frac{K_2 P_{\text{AlF}_3} P_{\text{H}_2\text{O}}^{3/2}}{P_{\text{HF}}^3} \quad (12)$$

This derivation suggests that the supersaturation ratio,  $\Sigma_T$ , can be controlled by adjusting the partial pressures of the input gases. As estimated graphically from the vapour pressure for growth (Fig. 2), adequate vapour pressure conditions of the reactant gases for the formation of wool-like whiskers were found to be:

$$P_{\text{AlF}_3} P_{\text{H}_2\text{O}}^{3/2} < 3.0 \times 10^{-3} \text{ torr}^2$$

Also, since the reaction was made of graphite, it is considered that the reaction  $\text{H}_2\text{O} + \text{C} = \text{CO} + \text{H}_2$ ,  $\Delta G^\circ = 26 \text{ kcal mol}^{-1}$  at 1700 K, takes place on the surface of graphite which leads to a decrease in the

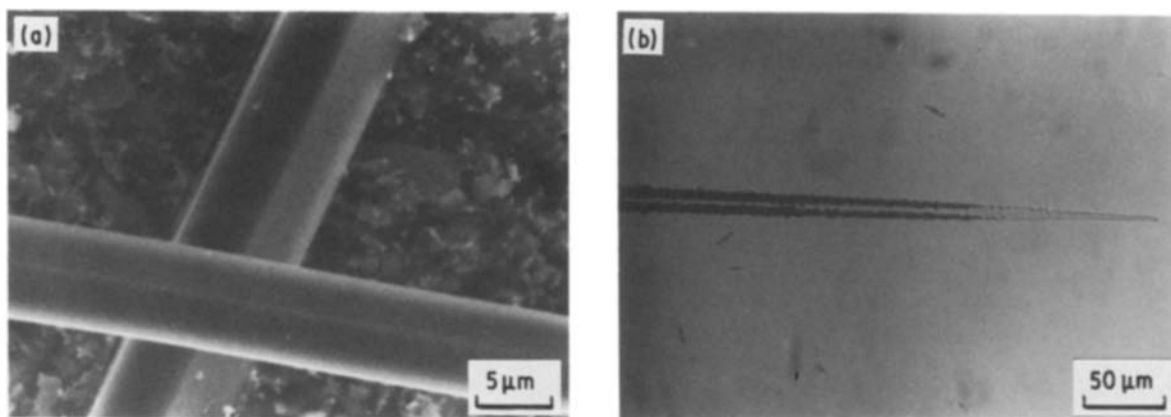


Figure 4 Optical micrographs of needle-like whiskers: (a) whiskers with hexagonal forms; (b) tapered whiskers.

vapour pressure of  $\text{H}_2\text{O}$ . Therefore, the actual vapour pressure of  $\text{H}_2\text{O}$  was considered to be lower than its calculated vapour pressure.

### 3.3. Morphology of products

The crystals formed were identified as  $\text{Al}_2\text{O}_3$  by X-ray diffraction and electron diffraction. Typical photographs and scanning electron micrographs of  $\text{Al}_2\text{O}_3$  whiskers are shown in Figs 3 and 4. Most whiskers grew straight and their side surfaces were generally smooth, but whiskers having kinks, branches or knots perpendicular to the growth direction were frequently observed (Figs 3b, c, and d). Furthermore, curved and bent filament-like whiskers tended to form easily under conditions of high carrier gas flow rate, due to the turbulence of gas flow around the substrate. Needle-like whiskers, which seem to be C-whiskers from observation of the well-developed side faces with hexagonal forms, were frequently observed under relatively high vapour pressures of  $\text{AlF}_3$  and  $\text{H}_2\text{O}$  (Fig. 4a). Two types of whisker could be formed: one type is that which had a uniform cross-section over its length, and the other is that which is tapered. The tapered whiskers shown in Fig. 4b seem to be  $A_2$ -whiskers in the  $[1\ 1\ \bar{2}\ 0]$  direction as reported by Sears and DeVries [11]. No impurities were detected by EPMA of whiskers formed under the usual conditions. Some whiskers formed under a high water vapour pressure, however, had glassy beads which were com-

posed of silicon and aluminium as a contaminant from the mullite tube, as shown in Fig. 5.

### 4. Conclusions

The vapour-phase growth of  $\text{Al}_2\text{O}_3$  whiskers by hydrolysis of aluminium fluoride vapour has been studied at  $1400^\circ\text{C}$ . Wool-like and needle-like whiskers, without accompanying platelet and dendrites, were grown on a polycrystalline alumina substrate. The wool-like whiskers grew to lengths of several millimetres with diameters of 1 to  $4\ \mu\text{m}$ , while the needle-like whiskers grew to lengths up to 12 mm with diameters of 10 to  $30\ \mu\text{m}$ . Wool-like whiskers were formed preferentially under conditions of low vapour pressures of the reactant gas, i.e.  $P_{\text{AlF}_3} \times P_{\text{H}_2\text{O}}^{3/2} < 3.0 \times 10^{-3}\ \text{torr}^2$ .

Most whiskers grew straight on the substrate under the usual conditions, but under conditions of the high carrier gas flow rate, curved and bent whiskers tended to grow more easily due to the nonuniform gas flow around the substrate. Furthermore, whiskers with kinks, branches or knots were also formed. The most frequently observed types were  $A_2$ -whiskers and C-whiskers.

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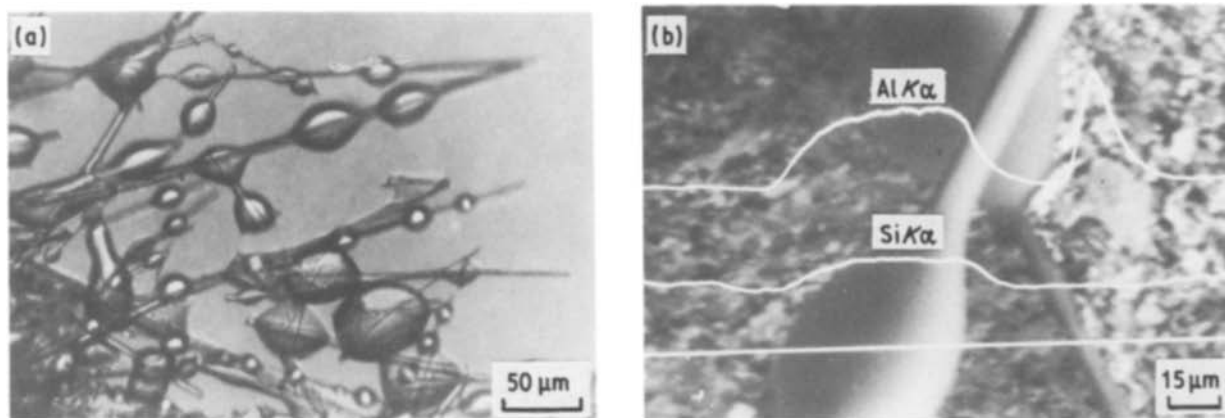


Figure 5 (a) Optical micrograph and (b) EPMA analysis of whiskers with glassy beads.

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